

October 2015

FJN4302R PNP Epitaxial Silicon Transistor with Bias Resistor

Features

- 100 mA Output Current Capability
- Built-in Bias Resistor ($R_1 = 10 \text{ k}\Omega$, $R_2 = 10 \text{ k}\Omega$)

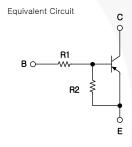
Applications

- Switching, Interface, and Driver Circuits
- Inverters
- · Digital Applications in Industrial Segments



Description

Transistors with built-in resistors can be excellent space- and cost-saving solutions by reducing component count and simplifying circuit design.



Ordering Information

Part Number	Top Mark	Package	Packing Method
FJN4302RTA	R4302	TO-92 3L	Ammo

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-50	V
V _{EBO}	Emitter-Base Voltage	-10	V
I _C	Collector Current	-100	mA
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 to 150	°C

Thermal Characteristics(1)

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
В	Power Dissipation	300	mW
P _D	Derate Above T _A = 25°C	2.4	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	416	°C/W

Note:

Electrical Characteristics

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -10 \mu A, I_E = 0$	-50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -100 \mu\text{A}, I_B = 0$	-50			V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = -40 \text{ V}, I_{E} = 0$			-0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = -5 \text{ V}, I_{C} = -5 \text{ mA}$	30			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$			-0.3	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$		200		MHz
C _{ob}	Output Capacitance	$V_{CB} = -10 \text{ V}, I_{E} = 0,$ f = 1.0 MHz		5.5		pF
V _I (off)	Input-Off Voltage	$V_{CE} = -5 \text{ V}, I_{C} = -100 \mu\text{A}$			-0.5	V
V _I (on)	Input-On Voltage	$V_{CE} = -0.3 \text{ V}, I_{C} = -10 \text{ mA}$	-3			V
R ₁	Input Resistor		7	10	13	kΩ
R_1/R_2	Resistor Ratio		0.9	1.0	1.1	

^{1.} PCB size: FR-4 76 x 114 x 0.6T mm³ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Typical Performance Characteristics

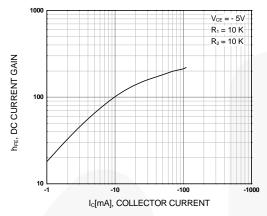


Figure 1. DC Current Gain

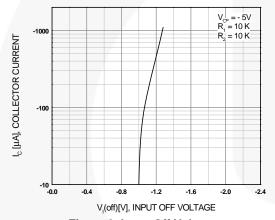


Figure 3. Input-Off Voltage

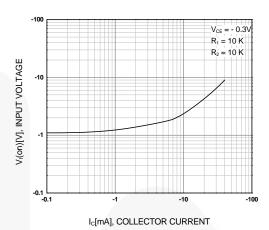


Figure 2. Input-On Voltage

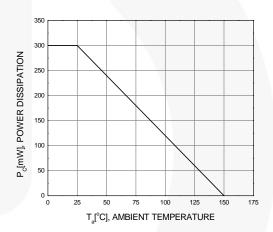
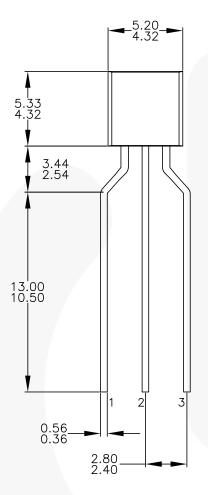
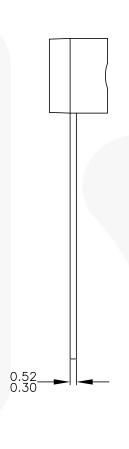
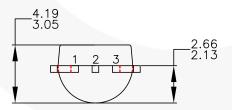


Figure 4. Power Derating

Physical Dimensions







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS—013, VARIATION AC.
 ALL DIMENSIONS ARE IN MILLIMETERS.
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Figure 5. 3-LEAD, TO-92, MOLDED 0.200 IN-LINE SPACING LD FORM





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Definition of Terms			
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